

MITSUBISHI LSTTLs

M74LS113AP

DUAL J-K NEGATIVE EDGE-TRIGGERED FLIP FLOP WITH SET

DESCRIPTION

The M74LS113AP is a semiconductor integrated circuit containing 2 J-K negative edge-triggered flip-flop circuits with discrete terminals for clock input \bar{T} , inputs J and K and direct set input \bar{S}_D .

FEATURES

- Negative edge-triggering
- Each flip-flop can be used independently
- Direct set input
- Q and \bar{Q} outputs
- Wide operating temperature range ($T_a = -20 \sim +75^\circ\text{C}$)

APPLICATION

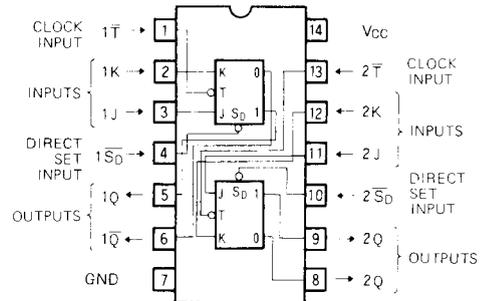
General purpose, for use in industrial and consumer equipment.

FUNCTIONAL DESCRIPTION

While \bar{T} is high, signals J and K are put in the read-in state, and when \bar{T} changes from high to low, the J and K signals immediately before the change emerge in outputs Q and \bar{Q} in accordance with the function table. By setting \bar{S}_D low, Q and \bar{Q} are set low and high respectively irrespective of the status of the other input signals. For use as a J-K flip-flop, \bar{S}_D must be kept high.

The only difference in functions from M74LS112AP is that this IC has no \bar{RD} input.

PIN CONFIGURATION (TOP VIEW)



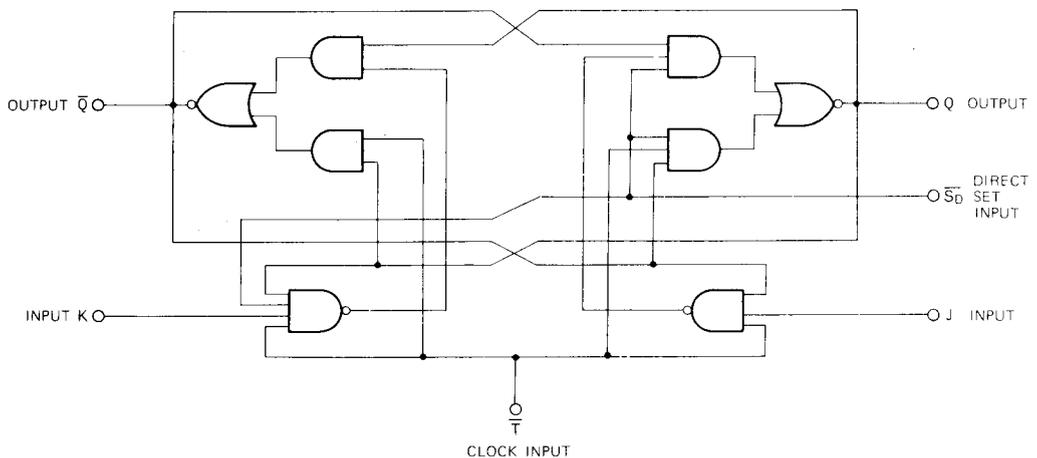
Outline 14P4

FUNCTION TABLE (Note 1)

T	\bar{S}_D	J	K	Q	\bar{Q}
X	L	X	X	H	L
↓	H	H	H	Toggle	
↓	H	L	H	L	H
↓	H	H	L	H	L
↓	H	L	L	Q^0	\bar{Q}^0
H	H	X	X	Q^0	\bar{Q}^0

Note 1: ↓ : Transition from high to low-level (negative edge trigger)
 X : Irrelevant
 Q^0 : level of Q before the indicated steady-state input conditions were established.
 \bar{Q}^0 : level of \bar{Q} before the indicated steady-state input conditions were established.
 Toggle : complement of previous state with ↓ transition of outputs

BLOCK DIAGRAM (EACH FLIP-FLOP)



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ABSOLUTE MAXIMUM RATINGS ($T_a = -20 \sim +75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Limits	Unit
V_{CC}	Supply voltage		$-0.5 \sim +7$	V
V_I	Input voltage		$-0.5 \sim +15$	V
V_O	Output voltage	High-level state	$-0.5 \sim V_{CC}$	V
T_{opr}	Operating free-air ambient temperature range		$-20 \sim +75$	$^\circ\text{C}$
T_{stg}	Storage temperature range		$-65 \sim +150$	$^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS ($T_a = -20 \sim +75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter		Limits			Unit
			Min	Typ	Max	
V_{CC}	Supply voltage		4.75	5	5.25	V
I_{OH}	High-level output current	$V_{OH} \geq 2.7\text{V}$	0		-400	μA
I_{OL}	Low-level output current	$V_{OL} \leq 0.4\text{V}$	0		4	mA
		$V_{OL} \leq 0.5\text{V}$	0		8	mA

ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter		Test conditions	Limits			Unit	
				Min	Typ *	Max		
V_{IH}	High-level input voltage			2			V	
V_{IL}	Low-level input voltage					0.8	V	
V_{IC}	Input clamp voltage		$V_{CC} = 4.75\text{V}, I_{IC} = -18\text{mA}$			-1.5	V	
V_{OH}	High-level output voltage		$V_{CC} = 4.75\text{V}, V_I = 0.8\text{V}$ $V_I = 2\text{V}, I_{OH} = -400\mu\text{A}$	2.7	3.4		V	
V_{OL}	Low-level output voltage		$V_{CC} = 4.75\text{V}$			0.25	0.4	V
			$V_I = 0.8\text{V}, V_I = 2\text{V}$			0.35	0.5	V
I_{IH}	High-level input current	J, K	$V_{CC} = 5.25\text{V}, V_I = 2.7\text{V}$				20	μA
		$\overline{S_D}$					60	
		\overline{T}					80	
		J, K		$V_{CC} = 5.25\text{V}, V_I = 10\text{V}$				0.1
$\overline{S_D}$					0.3			
\overline{T}					0.4			
I_{IL}	Low-level input current	J, K	$V_{CC} = 5.25\text{V}, V_I = 0.4\text{V}$				-0.4	mA
		$\overline{S_D}, \overline{T}$					-0.8	
I_{OS}	Short-circuit output current (Note 2)		$V_{CC} = 5.25\text{V}, V_O = 0\text{V}$				-20	mA
I_{CC}	Supply current		$V_{CC} = 5.25\text{V}$ (Note 3)		4		6	mA

* : All typical values are at $V_{CC} = 5\text{V}, T_a = 25^\circ\text{C}$

Note 2: All measurements should be done quickly and not more than one output should be shorted at a time.

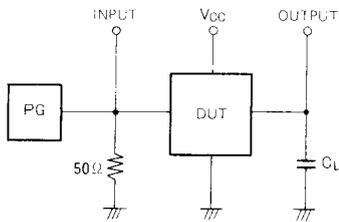
Note 3: Supply current measurements should be done with Q and \overline{Q} set alternately high and \overline{T} should be set low during actual measurement.

SWITCHING CHARACTERISTICS ($V_{CC} = 5\text{V}, T_a = 25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter		Test conditions	Limits			Unit
				Min	Typ	Max	
f_{max}	Maximum clock frequency		$C_L = 15\text{pF}$ (Note 4)	30	45		MHz
t_{PLH}	Low-to-high-level, high-to-low-level output propagation time, from \overline{T} to Q, \overline{Q}				8	20	ns
t_{PHL}	Low-to-high-level, high-to-low-level output propagation time, from \overline{T} to Q, \overline{Q}				7	20	ns
t_{PLH}	Low-to-high-level, high-to-low-level output propagation time, from $\overline{S_D}$ to Q, \overline{Q}				8	20	ns
t_{PHL}	Low-to-high-level, high-to-low-level output propagation time, from $\overline{S_D}$ to Q, \overline{Q}				7	20	ns

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Note 4: Measurement circuit

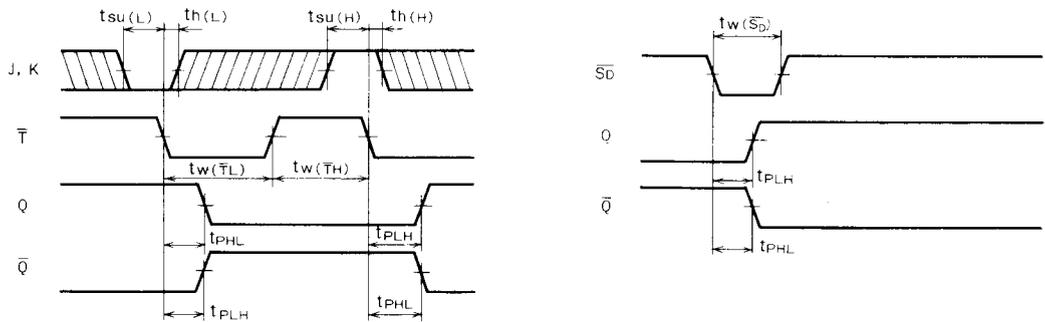


- (1) The pulse generator (PG) has the following characteristics:
 PRR = 1MHz, $t_r = 6ns$, $t_f < 6ns$, $t_w = 500ns$,
 $V_p = 3V_{p.p.}$, $Z_0 = 50\Omega$
- (2) C_L includes probe and jig capacitance.

TIMING REQUIREMENTS ($V_{CC} = 5V$, $T_a = 25^\circ C$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$t_w(\overline{T})$	Clock input \overline{T} high pulse width		20	13		ns
$t_w(S_D)$	Direct set pulse width		25	10		ns
t_r	Clock rise time			650	100	ns
t_f	Clock fall time			900	100	ns
$t_{SU}(H)$	Setup time high J, K to \overline{T}		20	9		ns
$t_{SU}(L)$	Setup time low J, K to \overline{T}		20	12		ns
$t_h(H)$	Hold time high J, K to \overline{T}		0	-10		ns
$t_h(L)$	Hold time low J, K to \overline{T}		0	-5		ns

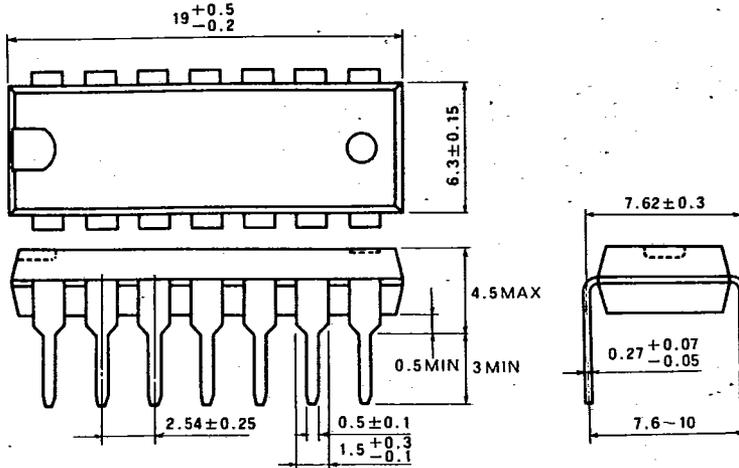
TIMING DIAGRAM (Reference level = 1.3V)



Note 5: The shaded areas indicate when the input is permitted to change for predictable output performance.

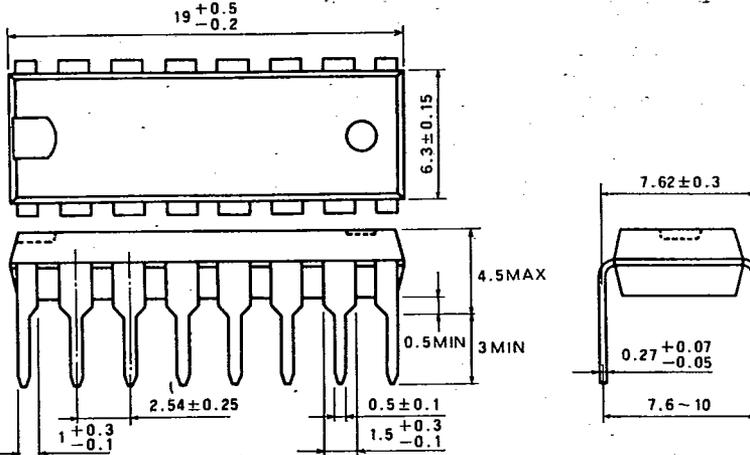
TYPE 14P4 14-PIN MOLDED PLASTIC DIL

Dimension in mm



TYPE 16P4 16-PIN MOLDED PLASTIC DIL

Dimension in mm



TYPE 20P4 20-PIN MOLDED PLASTIC DIL

Dimension in mm

